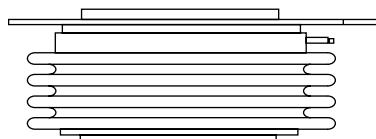


## Phase Control Thyristors (Hockey PUK Version), 1745 A



**A-24 (K-PUK)**

### FEATURES

- Center amplifying gate
- Metal case with ceramic insulator
- International standard case A-24 (K-PUK)
- High profile hockey PUK
- Lead (Pb)-free
- Designed and qualified for industrial level



**RoHS**  
COMPLIANT

### PRODUCT SUMMARY

$I_{T(AV)}$	1745 A
-------------	--------

### TYPICAL APPLICATIONS

- DC motor controls
- Controlled DC power supplies
- AC controllers

### MAJOR RATINGS AND CHARACTERISTICS

PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{T(AV)}$		1745	A
	$T_{hs}$	55	°C
$I_{T(RMS)}$		3200	A
	$T_{hs}$	25	°C
$I_{TSM}$	50 Hz	33 500	A
	60 Hz	35 100	
$I^2t$	50 Hz	5615	$kA^2s$
	60 Hz	5126	
$V_{DRM}/V_{RRM}$		800 to 1600	V
$t_q$	Typical	200	μs
$T_J$		- 40 to 125	°C

### ELECTRICAL SPECIFICATIONS

<b>VOLTAGE RATINGS</b>				
TYPE NUMBER	VOLTAGE CODE	$V_{DRM}/V_{RRM}$ , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	$V_{RSM}$ , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	$I_{DRM}/I_{RRM}$ MAXIMUM AT $T_J = T_J$ MAXIMUM mA
ST1230C..K	08	800	900	100
	12	1200	1300	
	14	1400	1500	
	16	1600	1700	

# ST1230C..KP Series

Vishay High Power Products Phase Control Thyristors  
(Hockey PUK Version), 1745 A



## ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS	
Maximum average on-state current at heatsink temperature	$I_{T(AV)}$	180° conduction, half sine wave double side (single side) cooled			1745 (700)	A	
					55 (85)	°C	
Maximum RMS on-state current	$I_{T(RMS)}$	DC at 25 °C heatsink temperature double side cooled			3200		
Maximum peak, one-cycle non-repetitive surge current	$I_{TSM}$	$t = 10 \text{ ms}$	No voltage reapplied	Sinusoidal half wave, initial $T_J = T_J$ maximum	33 500	A	
		$t = 8.3 \text{ ms}$			35 100		
		$t = 10 \text{ ms}$	100 % $V_{RRM}$ reapplied		28 200		
		$t = 8.3 \text{ ms}$			29 500		
Maximum $I^2t$ for fusing	$I^2t$	$t = 10 \text{ ms}$	No voltage reapplied		5615	$\text{kA}^2\text{s}$	
		$t = 8.3 \text{ ms}$			5126		
		$t = 10 \text{ ms}$	100 % $V_{RRM}$ reapplied		3971		
		$t = 8.3 \text{ ms}$			3625		
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1 \text{ to } 10 \text{ ms}$ , no voltage reapplied			56 150	$\text{kA}^2\sqrt{\text{s}}$	
Low level value of threshold voltage	$V_{T(TO)1}$	$(16.7 \% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$ , $T_J = T_J$ maximum			0.93	V	
High level value of threshold voltage	$V_{T(TO)2}$	$(I > \pi \times I_{T(AV)})$ , $T_J = T_J$ maximum			1.02		
Low level value of on-state slope resistance	$r_{t1}$	$(16.7 \% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$ , $T_J = T_J$ maximum			0.17	$\text{m}\Omega$	
High level value of on-state slope resistance	$r_{t2}$	$(I > \pi \times I_{T(AV)})$ , $T_J = T_J$ maximum			0.16		
Maximum on-state voltage	$V_{TM}$	$I_{pk} = 4000 \text{ A}$ , $T_J = T_J$ maximum, $t_p = 10 \text{ ms}$ sine pulse			1.62	V	
Maximum holding current	$I_H$	$T_J = 25 \text{ }^\circ\text{C}$ , anode supply 12 V resistive load			600	mA	
Typical latching current	$I_L$				1000		

## SWITCHING

PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum non-repetitive rate of rise of turned-on current	$dl/dt$	$Gate \text{ drive } 20 \text{ V}, 20 \Omega, t_r \leq 1 \mu\text{s}$ $T_J = T_J$ maximum, anode voltage $\leq 80 \% V_{DRM}$			1000	$\text{A}/\mu\text{s}$
Typical delay time	$t_d$	$Gate \text{ current } 1 \text{ A}, dl_g/dt = 1 \text{ A}/\mu\text{s}$ $V_d = 0.67 \% V_{DRM}, T_J = 25 \text{ }^\circ\text{C}$			1.9	$\mu\text{s}$
Typical turn-off time	$t_q$	$I_{TM} = 550 \text{ A}$ , $T_J = T_J$ maximum, $dl/dt = 40 \text{ A}/\mu\text{s}$ , $V_R = 50 \text{ V}$ , $dV/dt = 20 \text{ V}/\mu\text{s}$ , gate 0 V $100 \Omega$ , $t_p = 500 \mu\text{s}$			200	

## BLOCKING

PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum critical rate of rise of off-state voltage	$dV/dt$	$T_J = T_J$ maximum linear to 80 % rated $V_{DRM}$			500	$\text{V}/\mu\text{s}$
Maximum peak reverse and off-state leakage current	$I_{RRM}, I_{DRM}$	$T_J = T_J$ maximum, rated $V_{DRM}/V_{RRM}$ applied			100	mA



# ST1230C..KP Series

Phase Control Thyristors Vishay High Power Products  
(Hockey PUK Version), 1745 A

TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	
		TYP.	MAX.	UNITS	
Maximum peak gate power	P <sub>GM</sub>	T <sub>J</sub> = T <sub>J</sub> maximum, t <sub>p</sub> ≤ 5 ms	16		W
Maximum average gate power	P <sub>G(AV)</sub>	T <sub>J</sub> = T <sub>J</sub> maximum, f = 50 Hz, d% = 50	3		
Maximum peak positive gate current	I <sub>GM</sub>	T <sub>J</sub> = T <sub>J</sub> maximum, t <sub>p</sub> ≤ 5 ms		3.0	A
Maximum peak positive gate voltage	+ V <sub>GM</sub>			20	V
Maximum peak negative gate voltage	- V <sub>GM</sub>			5.0	
DC gate current required to trigger	I <sub>GT</sub>	T <sub>J</sub> = - 40 °C	Maximum required gate trigger/current/voltage are the lowest value which will trigger all units 12 V anode to cathode applied	200	mA
		T <sub>J</sub> = 25 °C		100	
		T <sub>J</sub> = 125 °C		50	
DC gate voltage required to trigger	V <sub>GT</sub>	T <sub>J</sub> = - 40 °C		1.4	V
		T <sub>J</sub> = 25 °C		1.1	
		T <sub>J</sub> = 125 °C		0.9	
DC gate current not to trigger	I <sub>GD</sub>	T <sub>J</sub> = T <sub>J</sub> maximum	Maximum gate current/voltage not to trigger is the maximum value which will not trigger any unit with rated V <sub>DRM</sub> anode to cathode applied	10	mA
DC gate voltage not to trigger	V <sub>GD</sub>			0.25	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum operating junction temperature range	T <sub>J</sub>			- 40 to 125	°C
Maximum storage temperature range	T <sub>Stg</sub>			- 40 to 150	
Maximum thermal resistance, junction to heatsink	R <sub>thJ-hs</sub>	DC operation single side cooled		0.042	K/W
		DC operation double side cooled		0.021	
Maximum thermal resistance, case to heatsink	R <sub>thC-hs</sub>	DC operation single side cooled		0.006	
		DC operation double side cooled		0.003	
Mounting force, ± 10 %				24 500 (2500)	N (kg)
Approximate weight				425	g
Case style		See dimensions - link at the end of datasheet		A-24 (K-PUK)	

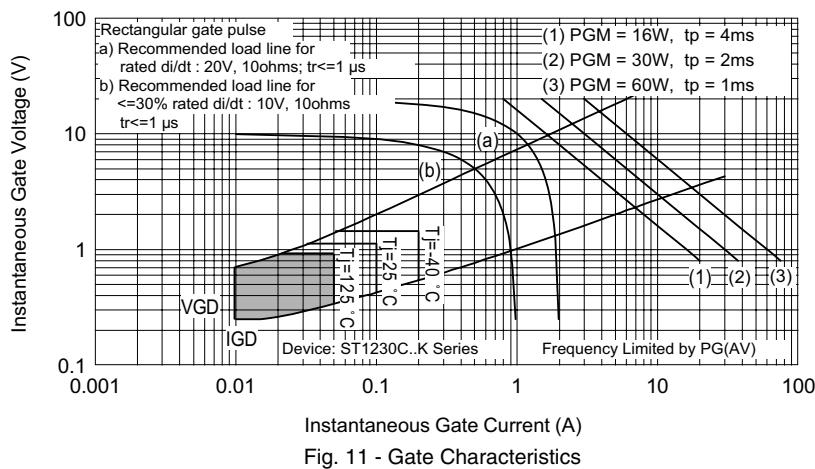
ΔR <sub>thJC</sub> CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION		RECTANGULAR CONDUCTION		TEST CONDITIONS	UNITS
	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE		
180°	0.003	0.003	0.002	0.002	T <sub>J</sub> = T <sub>J</sub> maximum	K/W
120°	0.004	0.004	0.004	0.004		
90°	0.005	0.005	0.005	0.005		
60°	0.007	0.007	0.007	0.007		
30°	0.012	0.012	0.012	0.012		

#### Note

- The table above shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC

# ST1230C..KP Series

Vishay High Power Products Phase Control Thyristors  
(Hockey PUK Version), 1745 A



Instantaneous Gate Current (A)

Fig. 11 - Gate Characteristics

## ORDERING INFORMATION TABLE

Device code	ST	123	0	C	16	K	1	-	P
	1	2	3	4	5	6	7	8	9

- 1** - Thyristor
- 2** - Essential part number
- 3** - 0 = Converter grade
- 4** - C = Ceramic PUK
- 5** - Voltage code x 100 =  $V_{RRM}$  (see Voltage Ratings table)
- 6** - K = PUK case A-24 (K-PUK)
- 7** - 0 = Eyelet terminals (gate and auxiliary cathode unsoldered leads)  
1 = Fast-on terminals (gate and auxiliary cathode unsoldered leads)  
2 = Eyelet terminals (gate and auxiliary cathode soldered leads)  
3 = Fast-on terminals (gate and auxiliary cathode soldered leads)
- 8** - Critical dV/dt: • None = 500 V/μs (standard selection)  
• L = 1000 V/μs (special selection)
- 9** - Lead (Pb)-free

### LINKS TO RELATED DOCUMENTS

Dimensions	<a href="http://www.vishay.com/doc?95081">http://www.vishay.com/doc?95081</a>
------------	---